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## Depressed Phase Transition in Solution-Grown VO<sub>2</sub> Nanostructures

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**Abstract:** The first-order metal—insulator phase transition in VO<sub>2</sub> is characterized by an ultrafast severalorders-of-magnitude change in electrical conductivity and optical transmittance, which makes this material an attractive candidate for the fabrication of optical limiting elements, thermochromic coatings, and Mott field-effect transistors. Here, we demonstrate that the phase-transition temperature and hysteresis can be tuned by scaling VO<sub>2</sub> to nanoscale dimensions. A simple hydrothermal protocol yields anisotropic freestanding single-crystalline VO<sub>2</sub> nanostructures with a phase-transition temperature depressed to as low as 32 °C from 67 °C in the bulk. The observations here point to the importance of carefully controlling the stochiometry and dimensions of VO<sub>2</sub> nanostructures to tune the phase transition in this system.

## Introduction

Nanoscale materials with at least one dimension smaller than 100 nm exhibit remarkable properties that are often not observed for their bulk counterparts.<sup>1,2</sup> The dramatic modifications to physical and chemical properties at nanoscale dimensions originates from quantum confinement effects, fairly subtle structural changes such as surface reconstruction and lattice expansion/contraction, or the increased contributions from atoms residing on the surface.<sup>3,4</sup> Much effort over the past decade has focused on elucidation of finite size effects in semiconductors;5 indeed, II-VI chalcogenide quantum dots represent a particularly well-developed example of the remarkable applications possible upon scaling materials to nanoscale dimensions.<sup>6</sup> The role of finite size in modifying the properties of transition metal oxides has only recently started to attract attention.<sup>7-9</sup> Vanadium oxides represent particularly attractive systems for such investigations because of their tremendous structural diversity arising from the facile accessibility of different vanadium oxidation states and their high tolerance for point defects.7,10-12 Apart from the stoichiometric phases VO, V<sub>2</sub>O<sub>3</sub>, VO<sub>2</sub>, and V<sub>2</sub>O<sub>5</sub>, a

\* National Institute of Standards and Technology.

- Ozin, G. A.; Arsenault, A. C. Nanochemistry: A Chemical Approach to Nanomaterials; Royal Society of Chemistry: Cambridge, UK, 2005; Vol. 1.
- (2) Alivisatos, A. P. J. Phys. Chem. 1996, 100, 13226.
- (3) Lieber, C. M. MRS Bull. 2003, 28, 486.
- (4) El-Sayed, M. Acc. Chem. Res. 2004, 37, 326.
- (5) Brus, L. E. Appl. Phys. A: Mater. Sci. Process. 1991, 53, 463.
- (6) Murray, C. B.; Kagan, C. R.; Bawendi, M. G. Annu. Rev. Mater. Sci. 2000. 30, 546.
- (7) Transition Metal Oxides; Rao, C. N. R., Raven, B., Eds.; VCH: New York, 1995.
- (8) Law, M.; Goldberger, J.; Yang, P. Annu. Rev. Mater. Res. 2004, 34, 83.
- (9) Synthesis, Properties, and Applications of Oxide Nanomaterials; 1st ed.; Rodriguez, J. A., Fernandez-Garcia, M., Eds.; Wiley-VCH: Weinheim, 2007.

closely related set of structures with the stoichiometry  $V_n O_{2n-1}$ and  $V_n O_{2n+1}$  are known that are able to accommodate point defects via means such as the formation of crystallographic shear structures. Arguably the two most notable compounds among the numerous vanadium oxides are V<sub>2</sub>O<sub>3</sub> and VO<sub>2</sub>, which have long been textbook examples of systems exhibiting well-defined metal-insulator phase transitions with changes in electrical conductivity ranging up to 5 orders of magnitude.<sup>13-15</sup> VO<sub>2</sub>, in particular, has attracted tremendous interest over almost half a century and is a benchmark problem in solid-state chemistry because of its near-room temperature metal-insulator phase transition at  $\sim$ 67 °C. The ultrafast first-order phase transition in VO<sub>2</sub> is also accompanied by a dramatic modification of the optical absorbance; below the phase-transition temperature VO<sub>2</sub> is a narrow bandgap semiconductor (bandgap of  $\sim 0.7 \text{ eV}$ ) and is transparent over the infrared region of the electromagnetic spectrum, whereas the higher temperature metallic phase of VO<sub>2</sub> is opaque at most frequencies. These remarkable coupled ordersof-magnitude near-room-temperature changes in optical and electrical properties make this material very attractive for applications such as Mott field-effect transistors, switching devices, optical waveguides, optical limiting elements, sensing components, and thermochromic coatings. 10,13,16-18

- (10) Surnev, S.; Ramsey, M. G.; Netzer, F. P. Prog. Surf. Sci. 2003, 73, 117.
- (11) Lopez, R.; Haynes, T. E.; Boatner, L. A.; Feldman, L. C.; Haglund, R. F., Jr. *Phys. Rev. B* **2002**, *65*, 224113/1.
- (12) Wang, Y.; Cao, G. Chem. Mater. 2006, 18, 2787.
- (13) Morin, F. J. Phys. Rev. Lett. 1959, 3, 34.
- (14) Zylbersztejn, A.; Mott, N. F. Phys. Rev. B 1975, 11, 4383.
- (15) Goodenough, J. B. J. Solid State Chem. 1971, 3, 490.
- (16) Winter, M.; Jurgen, O. B.; Spahr, M. E.; Novak, P. Adv. Mater. 1998, 10, 725.
- (17) Lopez, R.; Boatner, L. A.; Haynes, T. E.; Feldman, L. C.; Haglund, R. F., Jr. J. Appl. Phys. 2002, 92, 4031.
- (18) Lopez, R.; Feldman, L. C.; Haglund, R. F., Jr. Phys. Rev. Lett. 2004, 93, 177403/1.

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Figure 1. Monoclinic (distorted VO<sub>6</sub>) and tetragonal (undistorted VO<sub>6</sub>) polymorphs of vanadium(IV) oxide.

Interestingly, despite the strong theoretical and experimental interest in this material, a fundamental understanding of the origin of the phase transition in VO<sub>2</sub> remains elusive.<sup>19-21</sup> A rather vigorous and longstanding debate in the literature focuses on the relative importance of electron-lattice coupling and correlated electrons in triggering the ultrafast phase transition. Indeed, this phase transition has been variously ascribed to Mott-Hubbard or Peierls lattice distortion types (or even a mix of both!).<sup>14,19,20,22-24</sup> For instance, a recent cluster dynamical mean field theory study asserts that singlet pairing and strong Coulomb interactions are both required to open up a gap in the insulating phase upon cooling to the metal-insulator phasetransition temperature.<sup>25</sup> This model emphasizes a large redistribution of electron occupancies in favor of a nonbonding orbital (the  $d_{\parallel}$  band) derived from the hybridization of V  $3d_{xy}$  states with O 2p<sub>z</sub> levels and has drawn extensive support from recent photoemission and X-ray absorption studies.<sup>26,27</sup>

- (19) Wentzcovich, R. M.; Schulz, W. W.; Allen, P. B. *Phys. Rev. Lett.* **1994**, *72*, 3389.
- (20) Cavalleri, A.; Dekorsky, T.; Chong, H. H. W.; Kieffer, J. C.; Schoenlein, W. Phys. Rev. B 2004, 70, 161102/1.
- (21) Laad, M. S.; Craco, L.; Muller-Hartmann, E. Phys. Rev. B 2006, 73, 195120/1.
- (22) Stefanovich, G.; Perhament, A.; Stefanovich, D. J. Phys.: Condens. Matter 2000, 12, 8837.
- (23) Kim, H.-T.; Chae, B.-G.; Youn, D.-H.; Maeng, S.-L.; Kim, G.; Kang, K.-Y.; Lim, Y.-S. New J. Phys. 2004, 6, 51.
- (24) Kim, H.-T.; Lee, Y. W.; Kim, B.-G.; Chae, B.-G.; Yun, S. J.; Kang, K.-Y.; Han, K. J.; Yee, K.-J.; Lim, Y.-S. *Phys. Rev. Lett.* **2006**, 2006.
- (25) Biermann, S.; Poteryaev, A.; Lichtenstein, A. I.; Georges, A. Phys. Rev. Lett. 2005, 94, 026404.
- (26) Koethe, T. C.; Hu, Z.; Haverkort, M.; Schubler-Langeheine, C.; Venturini, F.; Brookes, N. B.; Tjernberg, O.; Reichelt, W.; Hsieh, H. H.; Lin, H.-J.; Chen, C. T.; Tjeng, L. H. *Phys. Rev. Lett.* **2006**, *97*, 116402/1.

According to the Peierls structural phase-transition model, a small structural change from an insulating antiferromagnetic monoclinic phase to a metallic paramagnetic tetragonal phase accompanies this phase transition with strong electron-lattice coupling contributing extensively to the observed changes in conductivity and optical transmittance.<sup>15</sup> Figure 1 shows the crystal structures of the (high temperature) tetragonal and (low temperature) monoclinic polymorphs of VO<sub>2</sub>. The tetragonal structure formed above the metal-insulator phase-transition temperature corresponds to a relatively more isotropic arrangement and is based on adjacent [VO<sub>6</sub>] octahedra sharing edges along the c-axis to form a hexagonal close-packed lattice with considerable V-V overlap.<sup>15</sup> In contrast, the unit cell is doubled in the insulating monoclinic phase because of a small distortion of the [VO<sub>6</sub>] octahedra yielding alternate long and short V-V bonds with reduction in symmetry to  $C_{2h}$  point group.<sup>15,28</sup> Notably, other theoretical models attempting to explain the metal-insulator phase transition in VO2 have emphasized the importance of electron-electron correlations.<sup>19</sup> This general view has been bolstered by recent work by Kim and co-workers, which very elegantly illustrates that the metal-insulator phase transition in  $VO_2$  can be induced by hole doping either via photoassisted hole excitation or by the application of an electric field without the need for a structural phase transition.<sup>23,24,29</sup> These authors have demonstrated the existence of a nonequilibrium metallic monoclinic phase that persists between the

- (28) Andersson, G. Acta Chem. Scand. 1954, 8, 1599.
- (29) Kim, H.-T.; Chae, B.-G.; Youn, D.-H.; Kim, G.; Kang, K.-Y.; Lee, S.-J.; Kim, K.-B.; Lim, Y.-S. Appl. Phys. Lett. 2005, 86, 242101/1.

<sup>(27)</sup> Haverkot, M.; Hu, Z.; Tanaka, A.; Reichelt, W.; Streltsov, S.; Korotin, M. A.; Anisimov, V. I.; Hsieh, H. H.; Lin, H.-J.; Chen, C. T.; Khomskii, D. I.; Tjeng, L. H. *Phys. Rev. Lett.* **2005**, *95*, 196404/1.

metal-insulator phase transition and the monoclinic-rutile structural phase-transition temperature.

For integration in room-temperature devices and coatings, regardless of the structural/electronic origin of the phase transition, there is considerable interest in being able to shift the metal-insulator phase transition in VO<sub>2</sub> to lower temperatures. Some recent findings by Feldman, Lopez, and co-workers suggest the intriguing possibility of tuning the phase-transition temperature and hysteresis in  $VO_2$  by scaling these systems to nanoscale dimensions. In a series of articles, these authors have indeed demonstrated a strong finite-size effect on the phasetransition temperature and hysteresis in VO2 nanostructures prepared by top-down methods such as laser ablation or ion implantation in SiO<sub>2</sub> matrices.<sup>11,17,18</sup> These authors have demonstrated that significant undercooling is required to induce the phase transition in their ion-implanted VO<sub>2</sub> nanostructures. Invoking a Martensitic-like behavior, they postulate that the elimination of defects that can serve as nucleation sites for the phase transition leads to the need for a stronger driving force (lower/higher temperature). Remarkably, however, for VO<sub>2</sub> nanostructures prepared by bottom-up methods such as chemical vapor deposition and especially by solution-chemistry approaches, the metal-insulator phase transition appears to be very significantly smeared out or even completely absent, making it difficult to understand the influence of finite size on the structural/electronic phase transition in these systems.<sup>30–33</sup> The absence or diminished magnitude of the characteristic metal-insulator phase transition has been variously attributed to local deviations in oxygen stoichiometries or strain imposed on nanostructures as a result of adhesion to underlying substrates.<sup>30,31</sup> Indeed, it is well known that the metal-insulator transition in  $VO_2$  is very sensitive to the stoichiometry and crystallinity of the measured systems.<sup>30,34,35</sup> In a recent investigation, Ramanathan and co-workers have carried out detailed measurements to correlate electron transport data directly to the band structure derived from near-edge X-ray absorption fine structure spectroscopy (NEXAFS) measurements for VO2 thin films fabricated by reactive sputtering of a V target.<sup>36</sup> These authors have found that the metal-insulator phase transition and the electron correlations involved in the phase transition depend sensitively on the oxygen stoichiometry-a change in the anion stoichiometry by a few percent can lead to several orders of magnitude difference in the phase-transition behavior. These findings underline the need to develop synthetic approaches that can yield free-standing nanostructures with careful control of these parameters. Here, we provide clear evidence for highly depressed phase transitions in anisotropic freestanding VO<sub>2</sub> nanostructures prepared by the hydrothermal cleavage of bulk VO<sub>2</sub> in the presence of aliphatic alcohols.

While several approaches for the fabrication of VO<sub>2</sub> nanostructures have been reported previously in the literature

- (30) Maeng, J.; Kim, T.-W.; Jo, G.; Lee, T. Mater. Res. Bull. 2008, 43, 1649.
- Wu, J.; Gu, Q.; Guiton, B. S.; Leon, N.; Ouyang, L.; Park, H. Nano (31)Lett. 2006, 2313.
- (32) Wu, X.; Tao, Y.; Dong, L.; Wang, Z.; Hu, Z. Mater. Res. Bull. 2005, 40. 315.
- (33) Liu, J.; Li, Q.; Wang, T.; Yu, D.; Li, Y. Angew. Chem., Int. Ed. 2004, 43, 5048.
- (34) Barker, A. S., Jr.; Verleur, H. W.; Guggenheim, H. J. Phys. Rev. Lett. 1966, 17, 1286.
- (35) Griffiths, C. H.; Eastwood, H. K. J. Appl. Phys. 1974, 45, 2201.
- (36) Ruzmetov, D.; Senanayake, S. D.; Narayanamurti, V.; Ramanathan, S. Phys. Rev. B 2008, 77, 195442/1.

including, rf sputtering, hydrothermal syntheses,32,33,37,38 controlled oxidation and sputtering, and vapor transport onto Si<sub>3</sub>N<sub>4</sub> substrates,<sup>30,39</sup> evidence for well-defined phase transitions has remained elusive. Here, we demonstrate well-defined structural phase transitions in VO<sub>2</sub> nanobelts and nanosheets grown from solution that are significantly depressed from the bulk VO<sub>2</sub> phase-transition temperature of ~67 °C to temperatures as low as 32 °C by modifying a synthetic approach that was originally used to prepare V<sub>2</sub>O<sub>4</sub>•0.25H<sub>2</sub>O nanowires.<sup>40</sup>

## **Experimental Section**

Synthesis. VO<sub>2</sub> nanostructures were synthesized solvothermally by the hydration/cleavage/exfoliation of bulk V2O4 (Sigma Aldrich, >99.5%) using Parr acid digestion bombs. Aliphatic alcohols used as structure-directing agents were obtained from Fisher. Deionized water from a Barnstead International NANOpure Diamond ultrapure water system ( $\rho = 18.2 \text{ M}\Omega/\text{cm}$ ) was used to prepare all aqueous solutions. In a typical reaction, 1.8 mmol of V<sub>2</sub>O<sub>4</sub> was mixed with 1 mL of the structure-directing species and 16 mL of deionized water. The resulting mixture was placed in a 23 mL Teflon cup that was then heated in a sealed autoclave at 210 °C for varying times (3-7 days). The precipitate obtained upon cooling to room temperature was washed with copious amounts of deionized water and acetone and then dried at ambient temperature.

Characterization. The morphologies of the resulting products were examined by scanning electron microscopy (SEM, JSM-5610LV and Hitachi SU-70 operated at 20 kV equipped with an energy dispersive X-ray analysis detector) and transmission electron microscopy (TEM, JEOL 2010 operated at 200 kV and JEOL 100CX operated at 100 kV). For TEM observations, the nanostructures were dispersed in 2-propanol solution and drop-cast onto 300 mesh carbon-coated Cu grids. Phase identification was performed using X-ray diffraction (XRD, Siemens D-500 with Cu Ka radiation,  $\lambda = 1.5418$  Å) with samples mounted using a machined glass slide sample holder. Differential scanning calorimetry (DSC, Q200 TA Instruments) measurements under a flowing gaseous nitrogen atmosphere over a temperature range from 20 to 150 °C were used to study the phase transitions in the as-prepared nanostructures over repeated heating/cooling cycles. The electronic structure of the VO2 nanostructures was studied by V L-edge and O K-edge NEXAFS measurements performed on the National Institute of Standards and Technology beamline U7A at the National Synchrotron Light Source of Brookhaven National Laboratory. A toroidal mirror spherical grating monochromator using a 1200 lines/ mm grating with a nominal energy resolution of  $\sim 0.1$  eV was used for these measurements. The spectra were acquired in partial electron yield mode using a channeltron electron multiplier located near the sample with the detector at an entrance grid bias of -200V to enhance surface sensitivity. A charge compensation gun was used to avoid sample charging. A vanadium mesh was used as a reference standard for calibration of the energy scale for each spectrum. To eliminate the effects of incident beam intensity fluctuations and monochromator absorption features, the partial electron yield signals were normalized using the drain current of a freshly evaporated gold mesh with 90% transmittance located along the path of the incident X-rays. For heating experiments, the samples were mounted onto a homemade holder constructed using tantalum foil with a welded thermocouple. All data here have been acquired at magic angle ( $\theta = 54.7^{\circ}$ ) incidence of the X-ray beam. Pre- and

- Whittaker, L.; Zhang, H.; Banerjee, S. J. Mater. Chem. 2009, 19, 2968. (38)(39) Guiton, B. S.; Gu, Q.; Prieto, A. L.; Gudiksen, M. S.; Park, H. J. Am.
- Chem. Soc. 2005, 127, 498. (40)
- Wei, M.; Sugihara, H.; Honma, I.; Ichihara, M.; Zhou, H. Adv. Mater. 2005, 17, 2964.

<sup>(37)</sup> Gui, Z.; Fan, R.; Mo, W.; Chen, X.; Yang, L.; Zhang, S.; Hu, Y.; Wang, Z.; Fan, W. Chem. Mater. 2002, 14, 5053.



*Figure 2.* SEM (left) and TEM (right) images of  $VO_2$  nanostructures prepared by the solvothermal reaction of bulk  $V_2O_4$  with (A,B) 2-propanol for 3 days, (C,D) methanol for 7 days, and (E,F) 1,3-butanediol for 7 days.

postedge normalization of the data were performed using the Athena suite of programs.

## **Results and Discussion**

Figure 2 shows SEM images of VO<sub>2</sub> nanostructures obtained upon the cleavage/exfoliation of bulk VO<sub>2</sub> using 1,3-butanediol, 2-propanol, and methanol as structure-directing agents. Anisotropic monoclinic VO<sub>2</sub> nanostructures have been obtained for all the alcohols listed in Table 1. Unlike V<sub>2</sub>O<sub>5</sub>, V<sub>6</sub>O<sub>13</sub>, and several hydrated vanadium oxides, monoclinic VO<sub>2</sub> (Figure 1) does not crystallize in a layered structure in the absence of hydration.<sup>15</sup> However, Wei and co-workers have demonstrated the preparation of hydrated  $V_2O_4 \cdot 0.25H_2O$  nanowires with a layered structure upon the hydrothermal treatment of monoclinic VO<sub>2</sub>.<sup>40</sup> Indeed, several layered hydrated structures of V<sub>2</sub>O<sub>4</sub> are known with water molecules residing in the interlayer spaces between [VO<sub>5</sub>] square pyramids.<sup>41</sup> Whittingham and co-workers first reported the synthesis of an intriguing layered tetragonal  $Li_xV_{2-\delta}O_{4-\delta}$ •H<sub>2</sub>O phase by the reaction of V<sub>2</sub>O<sub>5</sub> in acidic media with lithium and tetramethylammonium ions.  $^{41,42}$  These authors demonstrated that lithium ions could be electrochemically

Table 1.	DSC	Peaks	Measured	during	Cooling	and	Heating	for
VO <sub>2</sub> Nan	ostruc	tures						

structure-directing agent	DSC temperature range 20-150 °C			
and reaction time	cooling peak	heating peak		
1,3-butanediol 7 days	32.4 °C	60.2 °C		
4 17 1		60.2 °C		
methanol / days	37.9 °C	62.4 °C		
2-propanol 7 days	46.8 °C	65.8 °C		
		66.0 °C		
1,3-butanediol 3 days	57.9 °C	69.9 °C		
2-propanol 3 days	56.5 °C	70.1 °C 71.6 °C		
methanol 3 days	58.9 °C	71.9 °C 69.6 °C		
octanol 3 days	57.7 °C	69.9 °C 70.9 °C		
ethanol 3 days	58.3 °C	70.9 °C 69.5 °C		
1-butanol 3 days	59.7 °C	70.5 °C 69.6 °C 69.9 °C		

removed from this structure by delithiation while still essentially preserving the layered framework, suggesting the possible use of this phase as a cathode material for Li-ion batteries.<sup>42</sup> Several other layered vanadium oxide structures incorporating various cations and/or organic species have also been synthesized by

<sup>(41)</sup> Chirayil, T.; Zavalij, P.; Whittingham, M. S. Solid State Ionics 1996, 84, 163.

<sup>(42)</sup> Chirayil, T.; Zavalij, P.; Whittingham, M. S. J. Electrochem. Soc. 1996, 143, L193.



*Figure 3.* XRD patterns of VO<sub>2</sub> nanowires prepared by the hydrothermal treatment of bulk  $V_2O_4$  with (A) 2-propanol for 3 days, (B) methanol for 7 days, (C) 1,3-butanediol for 7 days. The vertical lines indicate the peak positions expected for monoclinic VO<sub>2</sub> from JCPDS Card no. 043-1051.

hydrothermal methods.43 The addition of simple aliphatic alcohols to the hydrothermal protocol originally devised by Wei et al. profoundly affects the morphology, crystal structure, and properties of the obtained structures.<sup>40</sup> Figure 2 illustrates the different morphologies obtained upon the hydrothermal treatment of bulk (micrometer-sized) V<sub>2</sub>O<sub>4</sub> powder with a closely related series of alcohols. Figure 2 also shows transmission electron microscopy images that further confirm the formation of ultrathin VO<sub>2</sub> nanostructures with smooth edges. Figure 3 illustrates powder XRD patterns acquired for these three samples. The XRD patterns can be indexed to monoclinic VO<sub>2</sub>(M) (Joint Committee on Powder Diffraction Standards (JCPDS) No. 043-1051). The strong intensity of the {011} reflections points to the strongly preferential growth direction of these structures, as has also been noted previously for VO<sub>2</sub> nanowires prepared at high temperatures by vapor transport.<sup>39</sup> Analysis of the peak position and broadening of the most-intense {011} reflection is particularly instructive. We note that the full width at half maxima (fwhm) of the {011} reflections increase from 0.090° for bulk VO<sub>2</sub> to 0.091° for nanostructures prepared using 2-propanol for 3 days, 0.183° for nanostructures prepared using methanol for 7 days, and 0.219° for nanostructures prepared using 1,3 butanediol for 7 days. This Debye-Scherrer broadening of the diffraction peaks arising from finite size effects can be clearly correlated to the depression in phasetransition temperature, as discussed in more detail below. An analogous trend of increased broadening is also observed for the other diffraction peaks across these three samples. The  $\{011\}$ reflection also consistently broadens with increasing reaction time, suggesting the cleavage of bulk VO<sub>2</sub> to smaller nanostructure dimensions. Furthermore, the {011} reflection is observed to shift slightly from  $2\theta = 27.850^{\circ}$  for bulk VO<sub>2</sub> to 27.393° for the VO<sub>2</sub> nanostructures prepared using 1,3 butanediol for 7 days, corresponding to an increase in the d spacing from 3.204 to 3.256 Å. The nanostructured samples consistently

show an increase in the *d* spacing for the {011} reflection, although the correlation to the phase-transition temperature is not as good as observed for the peak width. Lattice expansion with scaling to nanoscale dimensions has been observed previously for other transition metal oxides such as CeO<sub>2</sub> (incidentally with the same +4 oxidation state as VO<sub>2</sub>), especially for nanostructures synthesized at low temperatures, and has been attributed therein to increasing concentrations of point defects or the inclusion of lower-valence Ce<sup>3+</sup> ions.<sup>44,45</sup>

Notably, upon hydrothermal reaction for 7 days, 1,3-butanediol yields relatively short nanobelt-like structures with clearly faceted rectangular cross sections. The nanowires vary in length from several hundred nanometers to about 10  $\mu$ m and have lateral widths ranging from 58 to 200 nm with an average diameter of 160 nm. In contrast, after reaction for 7 days, methanol affords relatively longer "straw-like" nanobelts with faceted ends, as evidenced in Figure 2C. The widths of the nanobelts range from 84 to 250 nm with an average width of 224 nm. These nanowires can range up to 30  $\mu$ m in length. The hydrothermal reaction of bulk V2O4 with these alcohols for shorter periods of time on the order of 72 h does not yield uniform nanowires although irregularly shaped microstructures and some nanoparticulate material is observed. In contrast, 2-propanol yields nanobelt morphologies that can be up to several tens of micrometers long after hydrothermal reaction for 72 h with lateral dimensions that can range from 89 nm to almost 300 nm with an average width of 226 nm. These nanobelts are relatively thin with thicknesses typically less than 100 nm. Longer reactions times appear to cause disintegration of these nanowires to more irregular morphologies. The observed polydispersity is characteristic of hydrothermal reactions but the average dimensions do appear to be a function of the structure-directing agent and reaction time.

<sup>(43)</sup> Chirayil, T.; Zavalij, P.; Whittingham, M. S. Chem. Mater. 1998, 10, 2629.

<sup>(44)</sup> Tsunekawa, S.; Fukuda, T.; Kasuya, A. J. Appl. Phys. 2000, 87, 1318.

<sup>(45)</sup> Spanier, J. E.; Zhang, F.; Robinson, R. D.; Chan, S.-W.; Herman, I. P.

Phys. Rev. B: Condens. Matter 2001, 64, 245407/1.



*Figure 4.* (A) Lattice-resolved HRTEM image of an individual  $VO_2$  nanobelt derived from the hydrothermal treatment of bulk  $VO_2$  with 1,3-butanediol showing the separation between (011) planes. (B) SAED pattern acquired for the same nanobelt. (C) Low-resolution TEM image of the nanobelt. The top right inset shows a TEM image of several other nanobelts, whereas the bottom left inset shows a cross-sectional high-resolution SEM image of the rectangular faceted end of an individual nanobelt. (D) SEM image of the nanobelt sample.

Figure 4 shows high-resolution SEM, high-resolution transmission electron microscopy (HRTEM), selected area electron diffraction (SAED), and TEM images of VO2 nanobelts prepared by the hydrothermal treatment of bulk VO<sub>2</sub> with 1,3-butanediol for 7 days. The lattice-resolved HRTEM image and the indexed SAED pattern in Figure 4A and B corroborate the singlecrystalline nature of the nanostructures. The cross-sectional SEM image in Figure 4C illustrates the nanobelt-like morphology of these nanostructures. The observed broadening of XRD peaks and the finite-size-induced depression in phase-transition temperature discussed below are related to the smallest dimension, which for the nanostructures discussed here is not the lateral width but rather the height of the structures. In the case of the nanobelts fabricated using 1,3-butanediol, the lateral dimensions range between 58 and 200 nm with an average value of 160 nm. Figure 4C illustrates a typical nanobelt with an aspect ratio of  $\sim 16$ . The inset to Figure 4C shows a cross-sectional SEM image for a nanobelt from the sample indicating a thickness of  $\sim$ 26 nm, much smaller than the average width or length. The nanobelts and nanosheets are clearly electron-transparent in the TEM and SEM images in Figures 3 and 4, further corroborating their thin cross sections. Analogously, from cross-sectional SEM images the nanostructures prepared using methanol and 2-propanol have been deduced to have cross-sectional dimensions as low as  $\sim$ 50 and 90 nm, respectively. The cross-sectional and lateral dimensions have been deduced from TEM and crosssectional SEM measurements of about 40 nanowires using Image J image analysis software. For all structure-directing agents, hydrothermal treatment for longer periods of time leads to fragmentation to progressively smaller structures.

Analogous to the formation of nanowires from V<sub>2</sub>O<sub>4</sub>·0.25H<sub>2</sub>O and other layered structures, a hydration—exfoliation—splitting mechanism is likely to be involved in the formation of the nanowires.<sup>40</sup> According to this model, bulk V<sub>2</sub>O<sub>4</sub> is hydrated to form a layered compound such as  $V_2O_4 \cdot 0.5H_2O$  or  $V_{2-\delta}O_{4-\delta}$  · H<sub>2</sub>O wherein water molecules reside in the interstices between layers of [VO<sub>5</sub>] square pyramids.<sup>40,41</sup> Hagrman et al. have detailed the crystal structure of a hydrated VO<sub>2</sub> polymorph with water molecules intercalated in this fashion and Chirayil and co-workers have reported an analogous  $V_{2-\delta}O_{4-\delta}$ ·H<sub>2</sub>O phase.41,46 The intercalation of water as well as alcohol molecules in our syntheses eventually weakens the attraction between the layers and results in the cleavage and exfoliation of the hydrated layered structures into nanosheets. The nanosheets with adsorbed alcohols have been theoretically predicted to have a significant amount of built-in stress, which causes them to split or deform to yield different morphologies such as the nanobelt and faceted nanosheet morphologies obtained here.<sup>47</sup> The driving force for the deformation/splitting of the nanosheets is thought to be the lowering of energy upon relieving the tension intrinsic to the exfoliated sheets. Different from Zhou et al.,40 the addition of alcohols that have a higher affinity for binding V relative to H<sub>2</sub>O yields monoclinic VO<sub>2</sub> nanostructures rather than the hydrated V<sub>2</sub>O<sub>4</sub>•0.25H<sub>2</sub>O nanosheets reported previously in the literature.

Figure 5 shows DSC data acquired for the VO<sub>2</sub> nanostructures. The structural phase transition in VO<sub>2</sub> is first-order in nature and includes a substantial entropy component that has been estimated to range from 12.6 to 13.8 J mol<sup>-1</sup> K<sup>-1</sup>.<sup>48</sup> Two major contributions to the latent heat at the phase transition arise from the lattice distortion and the change in conduction electrons because of the discontinuity in the carrier density.<sup>49</sup> Thermal

- (48) Schilbe, P.; Maurer, D. Mater. Sci. Eng., A 2004, 370, 449.
- (49) Berglund, C. N.; Guggenheim, H. J. Phys. Rev. 1969, 185, 1022.

<sup>(46)</sup> Hagrman, D.; Zubieta, J.; Warren, C. J.; Meyer, L. M.; Treacy, M. M. J.; Haushalter, R. C. J. Solid State Chem. 1998, 138, 178.

 <sup>(47)</sup> Zhang, S.; Peng, L. M.; Chen, Q.; Du, G. H.; Dawson, G.; Zhou, W. Z. Phys. Rev. Lett. 2003, 91, 256103/1.



*Figure 5.* DSC curves obtained for VO<sub>2</sub> nanowires prepared by the hydrothermal treatment of bulk  $V_2O_4$  with (A) 2-propanol for 3 days, (B) methanol for 7 days, and (C) 1,3 butanediol for 7 days compared with the DSC trace measured for (D) the bulk  $V_2O_4$  precursor.

analysis studies in the literature show well-defined and reproducible peaks in plots of heat capacity versus temperature at  $\sim$ 67 °C for bulk monoclinic VO<sub>2</sub> samples prepared at high temperatures.50 No such exothermic/endothermic peaks are observed for a closely related metastable monoclinic VO<sub>2</sub>(B) phase that is often obtained under hydrothermal conditions.<sup>38</sup> Consistent with these observations, annealed (micrometer-sized) bulk VO<sub>2</sub> powder shows a well-defined phase transition at  $\sim 67$  $^{\circ}$ C in the heating cycle and at  $\sim$ 60–64  $^{\circ}$ C in the cooling cycle. In contrast, the hydrothermally prepared nanostructured monoclinic VO<sub>2</sub> samples show starkly different thermal behavior. For VO<sub>2</sub> nanowire samples prepared using 1,3-butanediol to cleave and exfoliate bulk  $VO_2$  for 7 days, the phase transition is shifted down to  $\sim 60$  °C during the heating cycle and to as low as 32 °C during the cooling cycle. The peaks characteristic of the phase transition are also significantly broadened, which may be a result of the polydispersity in nanostructure size in the samples as evidenced from Figures 2 and 4. Table 1 summarizes the positions of the observed DSC peaks during the heating/ cooling cycles for samples prepared using different aliphatic alcohols as structure-directing agents. The nanosheet samples prepared using methanol (after a reaction time of 3 days) show peaks attributable to the structural phase transition at  $\sim$ 62 and  $\sim$ 37 °C, respectively, during the heating and cooling cycles. Notably, the DSC peaks corresponding to the monoclinic→tetragonal phase transition are shifted to higher temperatures relative to the bulk during the heating cycle for the straw-like nanowires prepared using methanol as the structure-directing agent. The thermal analysis results are found to be eminently reproducible for different samples. Over different heating/ cooling cycles of the same sample, there are variations of less <2 °C in the DSC peaks. Since the nanostructures are heated only to  $\sim 150$  °C in these measurements, no sintering of the structures is expected or observed. A hysteresis in the phase transition between cooling and heating cycles is characteristic of the first-order structural transition in VO<sub>2</sub>. Notably, the hysteresis loop is observed to be much wider for all the samples upon scaling to nanoscale dimensions. This increased hysteresis is consistent with observations from Feldman and co-workers for VO<sub>2</sub> nanostructures grown by methods such as ion implantation although there is an important difference.<sup>17</sup> These authors have observed that the phase transition occurs at a higher temperature upon heating and at a lower temperature upon cooling when VO<sub>2</sub> is scaled to nanoscale dimensions. While we do note this behavior for the sample prepared using 2-propanol for 3 days, the samples showing the most dramatic changes in the phase transition behavior, prepared by hydrothermal treatment of bulk VO2 with 1,3-butanediol and methanol (Table 1), show a depression in the phase-transition temperature upon cooling but not upon heating. It remains unclear why the cooling transition is more affected than the heating transition upon scaling to finite size. Clearly, a universal theory to describe phase transitions in strongly correlated metal oxides will need to account for the finite size effects observed here. However, as noted in the introduction the situation is far from clear even for bulk VO<sub>2</sub>. Consistent with the observed depression in the phase-transition temperature being a finite size effect, Table 1 illustrates that increasing the reaction time from 3 to 7 days leads to increased depression of the phase-transition temperature for all the structure-directing agents screened in our experiments. An increased hydrothermal reaction time corresponds to greater splitting of the nanosheets and nanobelts to smaller dimensions (especially smaller vertical dimensions or heights for the nanobelts), which clearly leads to further depression of the phase-transition temperature. Notably, this trend still holds true even for the hydrothermal reaction of  $V_2O_4$  with 2-propanol where the clean nanosheet samples observed after 3 days are shredded to smaller irregular shaped fragments after hydrothermal reaction for 7 days. The phase-transition temperature is decreased by  $\sim 10$  °C from 57 to 47 °C during the cooling cycle upon increasing the hydrothermal treatment time. We note also an excellent correlation between the observed depression in the

<sup>(50)</sup> Salker, A. V.; Seshan, K.; Keer, H. V. Phys. Status Solidi A 1983, 75, K37.



*Figure 6.* V L edge  $(2p_{3/2}, 2p_{1/2})$  and O K edge  $(\pi^*, \sigma^*)$  NEXAFS data acquired at room temperature for VO<sub>2</sub> nanostructures prepared by hydrothermally treating bulk V<sub>2</sub>O<sub>4</sub> with (A) 2-propanol for 3 days, (B) methanol for 7 days, and (C) 1,3 butanediol for 7 days contrasted with (D) the spectra acquired for the bulk V<sub>2</sub>O<sub>4</sub> powder precursor.

phase-transition temperature and the peak widths of the {011} XRD reflections (Figure 3), corroborating that smaller nanostructures show a more severe depression in the phase-transition temperature.

Further characterization of the electronic structure and phase transition behavior of the obtained VO2 nanostructures comes from soft X-ray absorption spectroscopy measurements (Figure 6). NEXAFS is a powerful element-specific tool for probing the frontier orbitals of VO<sub>2</sub> based on the excitation of core hole states to partially filled and empty states.<sup>51</sup> Given the dipole selection rules for NEXAFS spectroscopy,  $\Delta l = \pm 1$  with changes in spin disallowed, the V L-edge NEXAFS spectra represent the d-projected unoccupied density of states and the O K-edge spectra represent the p-projected unoccupied density of states of the valence levels.<sup>36,52,53</sup> The strong hybridization of the O 2p levels with the finely structured V 3d levels makes NEXAFS an especially powerful probe of bonding and electronic structure in  $VO_2$ .<sup>26,27,53</sup> Figure 6 compares V L-edge and O K-edge spectra acquired for VO2 nanostructures and bulk VO<sub>2</sub>. The V L-edge region shows two peaks at 517 and 524 eV that can be attributed to  $V2p_{3/2} \rightarrow 3d$  and  $V 2p_{1/2} \rightarrow 3d$ transitions, respectively. Notably, the peak positions of the V L-edge peaks are known to shift by about 0.7 eV for each oxidation state.<sup>54</sup> The similarity in the lineshapes and peak positions (within  $\pm 0.2 \text{ eV}$ ) observed here confirms the retention of the V<sup>4+</sup> oxidation state in the nanostructures upon hydrothermal treatment. Indeed, the spin-orbit splitting of the 2p levels is ca. 6.6 eV for the VO2 nanostructures, exactly the same value derived from XAS studies of VO<sub>2</sub> single crystals. A shoulder to the V  $L_{III}$  peak is observed at  $\sim 515$  eV and is

suggestive of the excellent crystallinity of the samples.<sup>52</sup> This feature is more pronounced in single crystals of VO<sub>2</sub> but is absent in spectra acquired for VO<sub>2</sub> powders or polycrystalline thin films on  $Si_3N_4$ .<sup>52,53</sup> Ruzmetov et al. have observed that the sharpness of this feature is strongly correlated to the texture of their polycrystalline VO<sub>2</sub> films; distinctive satellite peaks are observed only for films showing excellent crystallinity with a relatively large grain size.53 The observation of pronounced shoulders especially for the nanosheet and faceted nanobelt samples prepared using 2-propanol and 1,3 butanediol, respectively, under magic angle incidence of the X-ray beam attest to the excellent crystallinity of the samples (and perhaps also to the presence of some preferred orientation). On the basis of Goodenough's description of the band structure of VO<sub>2</sub>,<sup>15</sup> the V L-edge absorption for the monoclinic insulating phase of VO<sub>2</sub> primarily describes transitions into d<sub>ll</sub> nonbonding levels, whereas the O K-edge spectra describe transitions into  $\pi^*$ ,  $\sigma^*$ , and d<sub>ll</sub> levels. The dipole selection rules for NEXAFS imply that the O K-edge is characterized by transitions from O 1s core levels to states possessing O 2p symmetry. The O 2p levels are strongly hybridized with V 3d levels and thus the O K-edge spectral features serve as a very precise probe of these finely structured states. The approximately octahedral crystal field in  $VO_2$  splits the V 3d levels into higher  $e_g$  and lower  $t_{2g}$  levels. In the high-temperature rutile phase with more symmetric VO<sub>6</sub> octahedra, the V  $3d_{z^2}$  and  $3d_{x^2-y^2}$  orbitals point directly toward the oxygen ligands (along the V-O-V axes) giving rise to strongly directional  $\sigma$  bonding interactions accompanied by a strong splitting of the bonding/antibonding levels.<sup>26,53</sup> Figure 7 illustrates the axes definitions used to describe the bonding interactions in VO<sub>2</sub>. Of the  $t_{2g}$  set of orbitals, the  $3d_{xz}$  and  $3d_{yz}$ orbitals point in between the ligands and are involved in  $\pi$ interactions. Since these interactions are weaker, the unfilled antibonding  $\pi^*$  states lie closer to the Fermi level at relatively lower energies in the conduction band (correspondingly, the filled  $\pi$  states lie higher in energy in the valence band). The

<sup>(51)</sup> Stohr, J. NEXAFS Spectroscopy; Springer: Berlin, 1992.

<sup>(52)</sup> Ruzmetov, D.; Senanayake, S. D.; Ramanathan, S. Phys. Rev. B 2007, 75, 195102/1.

<sup>(53)</sup> Abbate, M.; De Groot, F. M. F.; Fuggle, J. C.; Ma, Y. J.; T., C. C.; Sette, F.; Fujimori, A.; Ueda, Y.; Kosuge, K. *Phys. Rev. B* **1991**, *43*, 7263.

<sup>(54)</sup> Chen, J. G. Surf. Sci. Rep. 1997, 30, 1.



*Figure 7.* Molecular orbital diagram depicting the electronic structure of the two polymorphs of VO<sub>2</sub>. The left MO diagram corresponds to the undistorted metallic phase of VO<sub>2</sub>, whereas the diagram on the right shows the altered MO diagram upon transition to the distorted insulating phase of VO<sub>2</sub>.<sup>15</sup>

remaining orbital from the  $t_{2g}$  set, the V  $3d_{xy}$  orbital, points in between the ligands toward the nearest neighbor V atom and remains nonbonding in the high-temperature rutile phase. Figure 7 also shows a modified version of Goodenough's band structure diagram illustrating the position of the partially filled d<sub>ll</sub> band (overlapping with the  $\pi^*$  band) derived from the nonbonding V  $3d_{xy}$  orbital at the Fermi level in the metallic phase.<sup>15</sup> The distortion of the VO<sub>6</sub> octahedra upon cooling to the lower symmetry monoclinic phase gives rise to alternating long and short V-V bonds (Figure 1). The resulting dimerization of the vanadium chains along the crystallographic c axis and the twisting of the V-V axis drastically alters the band structure. As a result of this distortion and electron repulsions, the d<sub>ll</sub> band is split with the unoccupied part of the band being pushed past the  $\pi^*$  band edge in energy because of localized pairing interactions and the filled part of the d<sub>ll</sub> band dropping below the Fermi level as a result of singlet pairing in the dimers, thus opening up a bandgap for the insulating phase.<sup>53</sup> The HOMO-LUMO bandgap between this filled  $d_{\parallel}$  band and the unfilled  $\pi^*$ edge has been estimated to be  $\sim 0.7$  eV from photoemission spectroscopy and optical spectroscopy measurements.53,55 The NEXAFS spectra in the O K-edge region is characterized by two peaks that can be understood based on the band structure discussion presented above: in the insulating phase the lower energy spectral feature is a convolution of transitions to  $\pi^*$  and d<sub>ll</sub> states, whereas the higher energy resonance corresponds to transitions to  $\sigma^*$  states. In single crystal samples, transitions to the d<sub>ll</sub> states have been resolved as distinctive spectral features shifted to slightly higher energies from the  $\pi^*$  edge at specific polarizations of the incident beam.53 In NEXAFS spectra of powder and polycrystalline thin films of VO<sub>2</sub>, the averaging over different orientations smears out the distinctive  $\pi^*$  and d<sub>ll</sub> features and a broad convoluted peak is observed instead.<sup>36,38,52</sup> Compared to bulk  $V_2O_4$ , the  $\pi^*$  peak is clearly further broadened in the nanostructured samples. Reports in the literature point to strong variations in the relative intensities of the  $\sigma^*$  and  $\pi^*$ 

peaks.<sup>36</sup> The results observed here are similar to that of powders and sputtered VO<sub>2</sub> films with the  $\pi^*$  peak significantly stronger in intensity.<sup>36,56</sup> Ruzmetov et al. have observed increased broadening of the spectral features and greater spectral weight for the  $\sigma^*$  peak for VO<sub>2</sub> films with a smaller grain size.<sup>36,52</sup> Indeed, consistent with this notion, we observe relatively lower  $\pi^*/\sigma^*$  intensity ratios for the nanostructures (as compared to bulk VO<sub>2</sub>) and both spectral features evidence significantly increased broadening. Some of the observed broadening may originate from the greater number of [VO<sub>6</sub>] octahedra located at the nanowire/nanosheet surfaces where some distortions to bonding may be possible as a result of surface reconstruction or lattice expansion. The weakly structured features observed above 535 eV correspond to transitions from O 1s states to O 2p states hybridized with V 4s and 4p states. The not inconsiderable spectral weight in this region attests to the strong contribution of covalency to bonding in VO<sub>2</sub>, typical of early transition metal oxides.56

To probe the changes in band structure across the phase transition, V L-edge and O K-edge NEXAFS spectra have been acquired over a heating/cooling cycle for the VO<sub>2</sub> nanostructures showing the most pronounced depression in phase-transition temperature, samples prepared by the hydrothermal reaction of bulk VO<sub>2</sub> with 1,3-butanediol shown in Figure 4. Below the phase-transition temperature, the low-energy peak at the O K-edge is a convolution of transitions to  $\pi^*$  and d<sub>ll</sub> states as outlined above and shown schematically in Figure 7. However, above the phase-transition temperature, the band structure is dramatically modified and transitions into the  $d_{\!\!\!|\!|}$  band are no longer observed. In NEXAFS spectra of powder and polycrystalline thin film samples, this implies a significant narrowing of the low-energy feature at the O K-edge. 36,52 Indeed, Figure 8a shows that as the VO<sub>2</sub> nanowire samples are heated past 60 °C, there is a pronounced narrowing of the  $t_{2g}$  peak. The spectra can be clearly divided into two distinctive sets: the FWHMs of the t<sub>2g</sub> peaks in spectra acquired at 25, 40, and 60 °C are broadened by about 30% relative to that for spectra acquired at 80, 100, and 125 °C. The latter set of data show very similar lineshapes indicating that the phase transition is complete by 80 °C, as also indicated by the DSC data. Remarkably, the higher energy  $\sigma^*$  peaks derived from hybridization of O 2p states with V eg orbitals shift to slightly lower energies in the high-temperature spectra. This is consistent with literature data for VO<sub>2</sub> single crystals and confirms that the main changes to the band structure occur at the  $d_{\parallel}$  band and that the  $\sigma^*$  band is only very weakly modified by the phase transition.<sup>53</sup>

The NEXAFS data acquired during the cooling cycle further corroborate DSC observations of the sharply depressed phase-transition temperature and increased hysteresis for VO<sub>2</sub> nano-structures. The low-energy  $t_{2g}$  peak at the O K-edge remains consistently narrow from 125 to 40 °C and indeed only at 30 °C is the peak significantly broadened as a bandgap opens up for the insulating phase and transitions to the d<sub>II</sub> band are again convoluted with the  $\pi^*$  spectral feature. These observations are consistent with the 32 °C metal to insulator phase-transition temperature observed in DSC measurements. A smaller effect is seen at the V L-edge. Haverkort et al. have shown that the ~515 eV satellite peak to the V L<sub>III</sub> resonance is more pronounced for the insulating phase compared to the metallic phase with significantly greater dichroicity in angle-resolved

<sup>(55)</sup> Shin, S.; Suga, S.; Taniguchi, M.; Fujisawa, M.; Kanzaki, H.; Fujimori, A.; Daimon, H.; Ueda, Y.; Kosuge, K.; Kachi, S. *Phys. Rev. B* **1990**, *41*, 4993.

<sup>(56)</sup> deGroot, F. M. F. G., M.; Fuggle, J. C.; Ghijsen, J.; Sawatzky, G. A.; Peterson, H. Phys. Rev. B 1989, 40, 5715.



*Figure 8.* NEXAFS spectra acquired over a heating/cooling cycle for VO<sub>2</sub> nanowire samples prepared by hydrothermally treating bulk V<sub>2</sub>O<sub>4</sub> with 1,3butanediol for 7 days. The upper panel shows data upon heating at 30, 40, 60, 80, 100, and 125 °C. The inset shows the changes in the satellite peak at the V L<sub>III</sub> edge. The lower panel shows NEXAFS spectra taken while cooling the sample from 125 to 25 °C, which further corroborates the changes in the lineshapes of the  $\pi^*$  peak. The spectra in blue have been acquired at 30 and 25 °C, respectively, illustrating the increased hysteresis observed for the nanostructures.

measurements.<sup>27</sup> Indeed, for the VO<sub>2</sub> nanostructures a pronounced smearing of the satellite peak is noted for spectra acquired at 80, 100, and 125 °C during the heating cycle evidencing the presence of the metallic phase at these temperatures. The NEXAFS data thus demonstrate that the fundamental electronic structure of VO<sub>2</sub> is substantiatively preserved in the VO<sub>2</sub> nanostructures and that the peaks observed in the DSC traces can be correlated to changes in band structure across the metal—insulator phase transition. Depression of the phase transition in  $VO_2$  can have three different origins: doping with another transition metal (such as Ti or W), strain, and scaling to nanoscale dimensions. The relatively simple synthetic process described here does not use any other transition metals, and indeed, X-ray photoelectron spectroscopy (XPS) and EDX studies do not reveal the presence of any such impurities. The free-standing nature of the samples rules out substantive strain as the underlying origin for the strong depression in the phase-transition temperature. Indeed, as Lopez et al. have observed for VO2 nanostructures fabricated by ion implantation or other top-down approaches,<sup>11,17</sup> the changes in the phase-transition temperature likely arise from the nanoscale dimensions of the VO<sub>2</sub> nanostructures prepared here.<sup>11,17,18</sup> The clear correlation observed between the depression in phasetransition temperature and (a) the peak broadening of the  $\{011\}$ diffraction peaks and (b) the smallest observed dimensions of the nanowires (as determined by cross-sectional SEM) provide strong evidence that this is indeed the case. Specifically, the sample prepared using 1,3-butanediol exhibiting the strongest depression in the phase-transition temperature shows the greatest broadening of the {011} reflection (0.219° vs 0.090° for bulk VO<sub>2</sub>) and the smallest average diameter (~160 nm) and crosssectional height (<60 nm). Furthermore increased reaction times clearly lead to a more severe depression in the phase-transition temperature consistent with the cleavage/fragmentation of the nanostructures to progressively smaller dimensions. Feldman and co-workers have proposed that with elimination of defects due to scaling to nanoscale dimensions, significant undercooling is required to nucleate/induce the phase transition, thus leading to a much broader hysteresis. However, as noted in preceding sections, considerable controversy still lingers over the fundamental origin of the phase transition even for bulk  $VO_2$ , and thus the mechanism by which factors such as defect density or lattice expansion can modify the phase transition behavior remains unclear. Nevertheless, careful control of the stoichiometry is essential to observe the phase transition. As noted above, the metal-insulator phase transition is very sensitive to the oxygen stoichiometry, 35,36 which may be the reason clear and well-defined phase transitions have not been observed for most nanostructured material reported thus far in the literature. Consistent with the close control of VO<sub>2</sub> stoichiometry discussed above, upon increasing the alcohol concentration by 100%, the

obtained nanostructures do not yield well-defined phase transitions. This is likely a result of the partial reduction of VO<sub>2</sub> by the alcohol molecules locally yielding  $V^{3+}$  domains.

In summary, we report strong finite size effects on the metal-insulator phase transition in free-standing single-crystalline nanostructures of VO2. The phase transition has been depressed to as low as 32 °C in VO<sub>2</sub> nanostructures from the 67 °C observed in the bulk. Close control of the stoichiometry finally enables the observation of finite size effects on the  $VO_2$ phase transition in solution-grown nanostructures that have hitherto only been observed in structures prepared by top-down methods or embedded in matrices. Further advances in dynamical mean field theory are required to help provide a deeper understanding of the phase transition in strongly correlated VO<sub>2</sub> and to perhaps develop a universal theory for metal-insulator phase transitions in strongly correlated metal oxides. The unprecedented depressed phase transitions observed for VO<sub>2</sub> nanowires paves the way for their use in optical waveguides, Mott field-effect transistors, sensing elements and as components for thermochromic coatings.

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